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<u>Diodes Incorporated</u> <u>DMP2012SN-7</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Datasheet of DMP2012SN-7 - MOSFET P-CH 20V 700MA SC59-3

Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com





DMP2012SN

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on)}	I _D T _A = +25°C
-20V	0.3Ω @ V _{GS} = -4.5V	-0.9A
-20V	0.5Ω @ V _{GS} = -2.5V	-0.7A

Description

This MOSFET has been designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power management functions

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- · Qualified to AEC-Q101 Standards for High Reliability

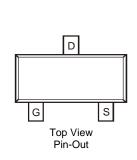
Mechanical Data

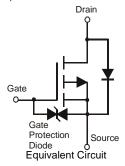
- Case: SC59
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin annealed over Copper leadframe.
 Solderable per MIL-STD-202, Method 208 <a>3
- Terminal Connections: See Diagram
- Weight: 0.014 grams (approximate)





Top View





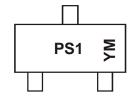
Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMP2012SN-7	Standard	SC59	3000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



PS1 = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017	2018
Code	Т	U	V	W	Χ	Υ	Z	Α	В	С	D	Е	F
Month	Jan	Feb	Mar	Apr	Мау	Jun	J	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	2	1	5	6		7	Ω	Q	0	N	٦



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DMP2012SN

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V_{DSS}	-20	V
Gate-Source Voltage	V_{GSS}	±12	V
Drain Current (Note 5) Steady State	I _D	-0.7	Α
Pulsed Drain Current (Note 6)	I _{DM}	-2.8	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P_{D}	500	mW
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	250	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	_		V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-10	μΑ	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Body Leakage	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 12V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	$V_{GS(th)}$	-0.5		-1.2	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance	R _{DS} (ON)	_	0.23	0.30	Ω	$V_{GS} = -4.5V, I_D = -0.4A$	
			0.37	0.50	_	$V_{GS} = -2.5V, I_D = -0.4A$	
Forward Transfer Admittance	Y _{fs}	_	1.5	_	S	$V_{DS} = -10V, I_{D} = -0.4A$	
Diode Forward Voltage (Note 7)	V _{SD}	_	-0.8	-1.1	V	$V_{GS} = 0V$, $I_{S} = -0.7A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C _{iss}	_	178.5	_	pF	\/ 40\/ \/ 0\/	
Output Capacitance	Coss	_	26.3		pF	$V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	18.8		pF	1 = 1.0WHZ	
SWITCHING CHARACTERISTICS							
Turn-On Delay Time	t _{D(ON)}	I	10.4	ı	ns		
Turn-Off Delay Time	t _{D(OFF)}	I	175	1	ns	$V_{DD} = -10V, I_D = -0.4A,$	
Turn-On Rise Time	t _r	_	22.3	_	ns	$V_{GS} = -5.0V$, $R_{GEN} = 50\Omega$	
Turn-Off Fall Time	t _f	_	64	_	ns		

Notes:

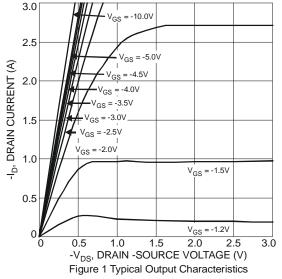
- 5. Device mounted on FR-4 PCB.
- 6. Pulse width ≤10µS, Duty Cycle ≤1%.
- 7. Short duration pulse test used to minimize self-heating effect.

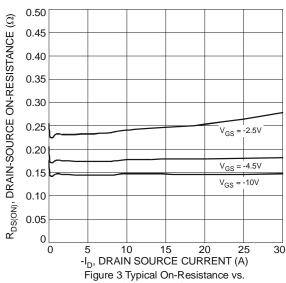
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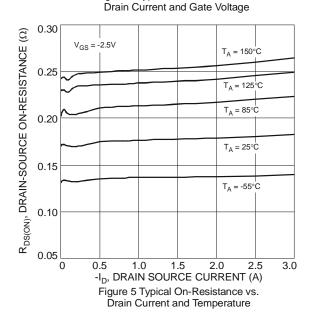
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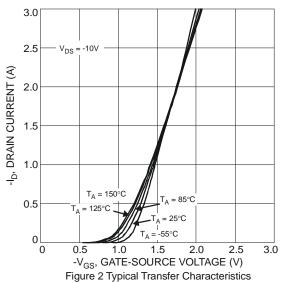


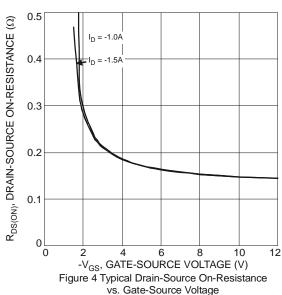
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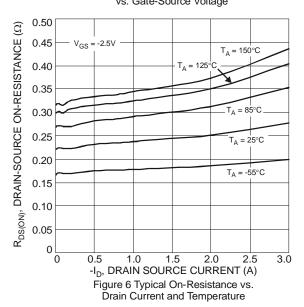




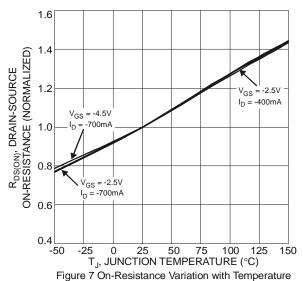


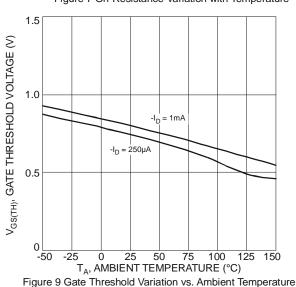




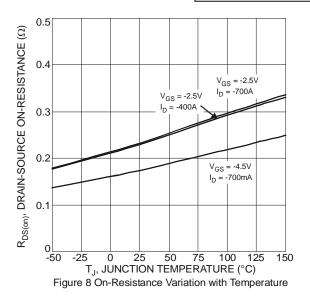


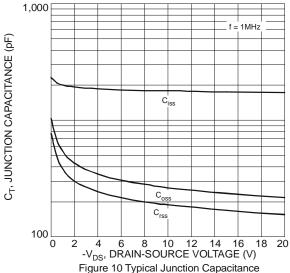






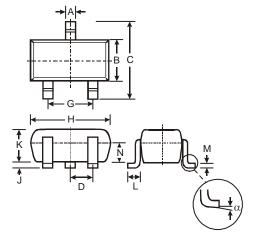
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Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SC59							
Dim	Min	Max	Тур				
Α	0.35	0.50	0.38				
В	1.50	1.70	1.60				
С	2.70	3.00	2.80				
D	-	-	0.95				
G			1.90				
Н	2.90	3.10	3.00				
J	0.013	0.10	0.05				
K	1.00	1.30	1.10				
L	0.35	0.55	0.40				
М	0.10	0.20	0.15				
N	0.70	0.80	0.75				
α	0°	8°	-				
All	All Dimensions in mm						

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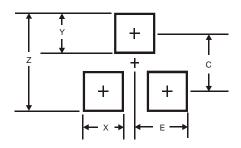
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Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	3.4
Х	0.8
Υ	1.0
С	2.4
E	1.35

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